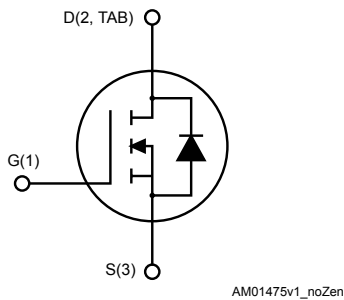


N-channel 550 V, 0.150 Ω typ., 16 A MDmesh™ M5 Power MOSFETs in a DPAK and TO-220 packages



DPAK

TO-220



Features

| Order code | V_{DS} @ $T_{jmax.}$ | $R_{DS(on)max.}$ | Package |
|------------|---------------------------|------------------|---------|
| STD18N55M5 | 600 V | 0.192 Ω | DPAK |
| STP18N55M5 | | | TO-220 |

- Extremely low $R_{DS(on)}$
- Low gate charge and input capacitance
- Excellent switching performance
- 100% avalanche tested

Applications

- Switching applications

Description

These devices are N-channel Power MOSFETs based on the MDmesh™ M5 innovative vertical process technology combined with the well-known PowerMESH™ horizontal layout. The resulting products offer extremely low on-resistance, making them particularly suitable for applications requiring high power and superior efficiency.

Product status link

[STD18N55M5](#)
[STP18N55M5](#)

1 Electrical ratings

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|----------------|---|------------|------------------|
| V_{GS} | Gate-source voltage | ± 25 | V |
| I_D | Drain current (continuous) at $T_C = 25\text{ }^\circ\text{C}$ | 16 | A |
| I_D | Drain current (continuous) at $T_C = 100\text{ }^\circ\text{C}$ | 10 | A |
| $I_{DM}^{(1)}$ | Drain current (pulsed) | 64 | A |
| P_{TOT} | Total dissipation at $T_C = 25\text{ }^\circ\text{C}$ | 110 | W |
| $dv/dt^{(2)}$ | Peak diode recovery voltage slope | 15 | V/ns |
| T_j | Operating junction temperature range | -55 to 150 | $^\circ\text{C}$ |
| T_{stg} | Storage temperature range | | |

1. Pulse width limited by safe operating area.

2. $I_{SD} \leq 16\text{ A}$, $di/dt \leq 400\text{ A}/\mu\text{s}$; $V_{DS\ peak} < V_{(BR)DSS}$; $V_{DD} = 340\text{ V}$.

Table 2. Thermal data

| Symbol | Parameter | Value | | Unit |
|---------------------|-------------------------------------|-------|--------|---------------------------|
| | | DPAK | TO-220 | |
| $R_{thj-case}$ | Thermal resistance junction-case | 1.14 | | $^\circ\text{C}/\text{W}$ |
| $R_{thj-amb}$ | Thermal resistance junction-ambient | | 62.5 | $^\circ\text{C}/\text{W}$ |
| $R_{thj-pcb}^{(1)}$ | Thermal resistance junction-pcb | 50 | | $^\circ\text{C}/\text{W}$ |

1. When mounted on an 1-inch² FR-4, 2oz Cu board.

Table 3. Avalanche characteristics

| Symbol | Parameter | Value | Unit |
|----------|--|-------|------|
| I_{AR} | Avalanche current, repetitive or not-repetitive (pulse width limited by $T_j\text{ Max}$) | 4 | A |
| E_{AS} | Single pulse avalanche energy (starting $T_j = 25\text{ }^\circ\text{C}$, $I_D = I_{AR}$, $V_{DD} = 50\text{ V}$) | 210 | mJ |

2 Electrical characteristics

($T_{CASE} = 25\text{ °C}$ unless otherwise specified)

Table 4. On/off states

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|---------------|-----------------------------------|---|------|-------|-----------|---------------|
| $V_{(BR)DSS}$ | Drain-source Breakdown voltage | $I_D = 1\text{ mA}, V_{GS} = 0\text{ V}$ | 550 | | | V |
| I_{DSS} | Zero gate voltage drain current | $V_{GS} = 0\text{ V}, V_{DS} = 550\text{ V}$ | | | 1 | μA |
| | | $V_{GS} = 0\text{ V}, V_{DS} = 550\text{ V}, T_C = 125\text{ °C}^{(1)}$ | | | 100 | μA |
| I_{GSS} | Gate body leakage current | $V_{DS} = 0\text{ V}, V_{GS} = \pm 25\text{ V}$ | | | ± 100 | nA |
| $V_{GS(th)}$ | Gate threshold voltage | $V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$ | 3 | 4 | 5 | V |
| $R_{DS(on)}$ | Static drain-source on resistance | $V_{GS} = 10\text{ V}, I_D = 8\text{ A}$ | | 0.150 | 0.192 | Ω |

1. Defined by design, not subject to production test.

Table 5. Dynamic

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|-------------------|---------------------------------------|---|------|------|------|---------------|
| C_{iss} | Input capacitance | $V_{DS} = 100\text{ V}, f = 1\text{ MHz}, V_{GS} = 0\text{ V}$ | - | 1260 | - | μF |
| C_{oss} | Output capacitance | | | 42 | | |
| C_{rss} | Reverse transfer capacitance | | | 3.6 | | |
| $C_{o(tr)}^{(1)}$ | Equivalent capacitance time related | $V_{DS} = 0\text{ to }440\text{ V}, V_{GS} = 0\text{ V}$ | - | 103 | - | μF |
| $C_{o(er)}^{(2)}$ | Equivalent capacitance energy related | | | 35 | | |
| R_g | Gate input resistance | $f = 1\text{ MHz}$ open drain | - | 2.8 | - | Ω |
| Q_g | Total gate charge | $V_{DD} = 440\text{ V}, I_D = 8\text{ A}, V_{GS} = 0\text{ to }10\text{ V}$ (see Figure 18. Test circuit for gate charge behavior) | - | 31 | - | nC |
| Q_{gs} | Gate-source charge | | | 8.3 | | |
| Q_{gd} | Gate-drain charge | | | 14.2 | | |

1. Time related is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS} .

2. Energy related is defined as a constant equivalent capacitance giving the same stored energy as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS} .

Table 6. Switching times

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|--------------|--------------------|---|------|------|------|------|
| $t_{d(v)}$ | Voltage delay time | $V_{DD} = 400\text{ V}$, $I_D = 10.5\text{ A}$, $R_G = 4.7\ \Omega$, $V_{GS} = 10\text{ V}$ (see Figure 19. Test circuit for inductive load switching and diode recovery times and Figure 22. Switching time waveform) | - | 37 | - | ns |
| $t_{r(v)}$ | Voltage rise time | | | 7 | | |
| $t_{c(off)}$ | Crossing time | | | 10.3 | | |
| $t_{f(i)}$ | Current fall time | | | 8.3 | | |

Table 7. Source drain diode

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|-----------------|-------------------------------|---|------|------|------|---------------|
| I_{SD} | Source-drain current | | - | | 16 | A |
| $I_{SDM}^{(1)}$ | Source-drain current (pulsed) | | | | 64 | |
| $V_{SD}^{(2)}$ | Forward on voltage | $I_{SD} = 16\text{ A}$, $V_{GS} = 0\text{ V}$ | - | | 1.5 | V |
| t_{rr} | Reverse recovery time | $I_{SD} = 16\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$ $V_{DD} = 100\text{ V}$ (see Figure 19. Test circuit for inductive load switching and diode recovery times) | - | 244 | | ns |
| Q_{rr} | Reverse recovery charge | | | 2.8 | | μC |
| I_{RRM} | Reverse recovery current | | | 23 | | A |
| t_{rr} | Reverse recovery time | $I_{SD} = 16\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$ $V_{DD} = 100\text{ V}$, $T_j = 150\text{ }^\circ\text{C}$ (see Figure 19. Test circuit for inductive load switching and diode recovery times) | - | 295 | | ns |
| Q_{rr} | Reverse recovery charge | | | 3.7 | | μC |
| I_{RRM} | Reverse recovery current | | | 25 | | A |

1. Pulse width limited by safe operating area.
2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%.

2.1 Electrical characteristics curves

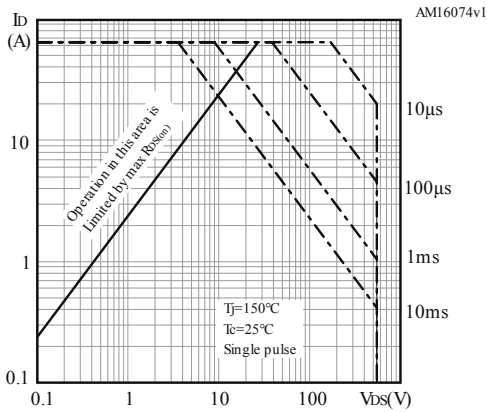
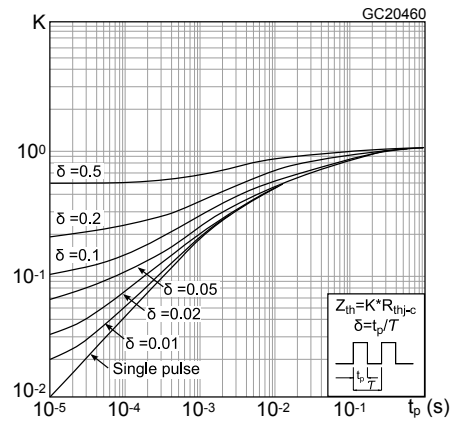
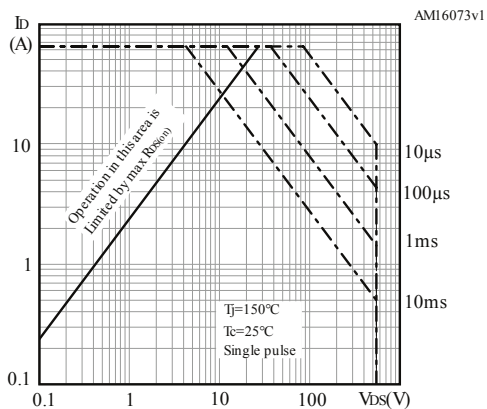
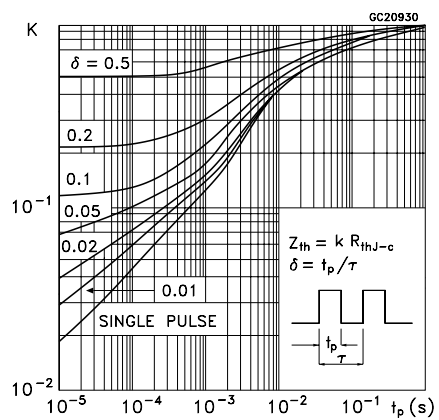
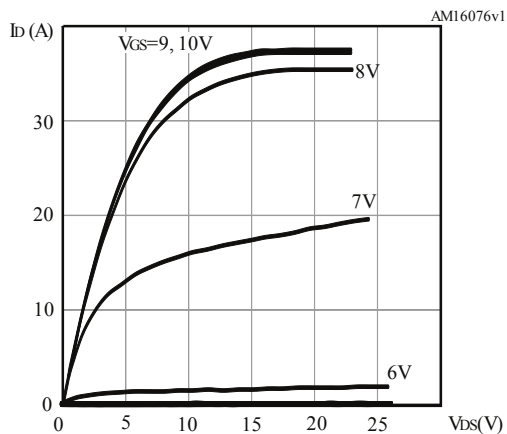
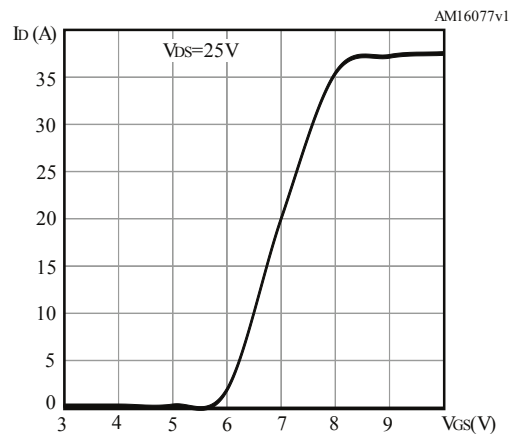
Figure 1. Safe operating area for DPAK

Figure 2. Thermal impedance DPAK

Figure 3. Safe operating area for TO-220

Figure 4. Thermal impedance for TO-220

Figure 6. Output characteristics

Figure 7. Transfer characteristics


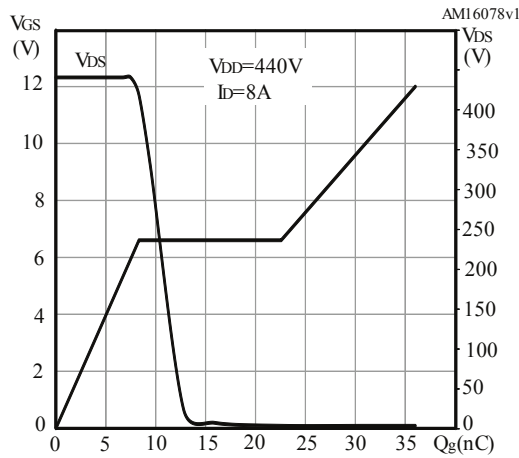
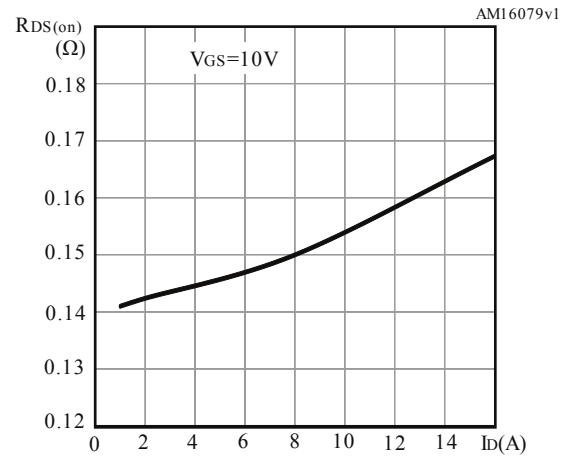
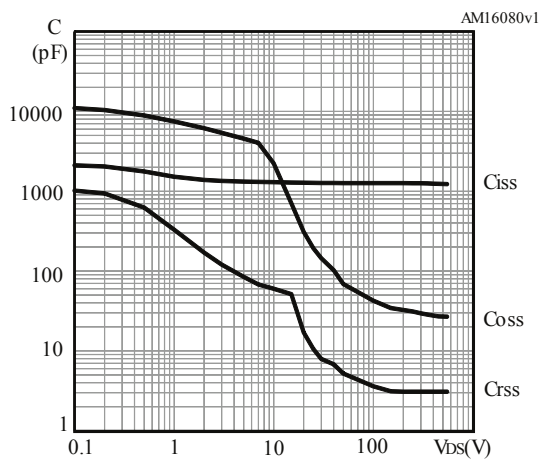
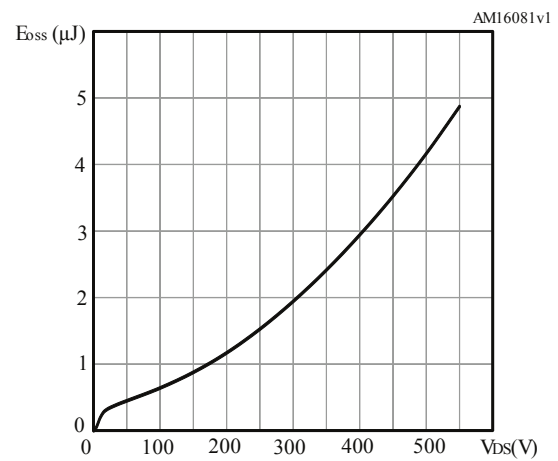
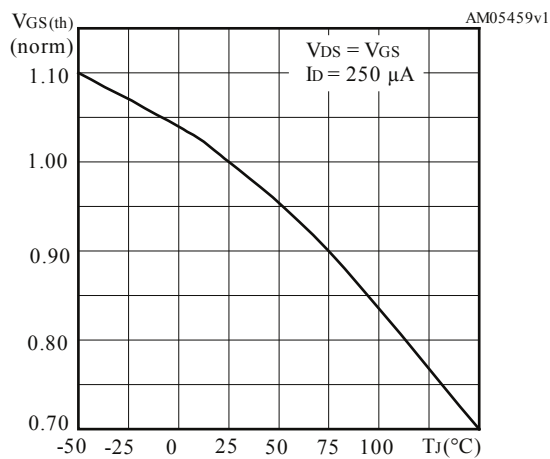
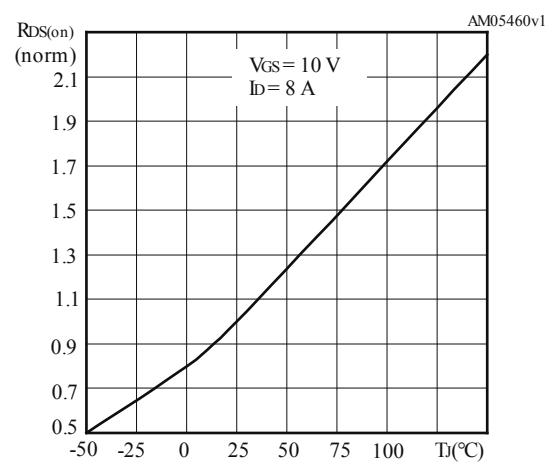
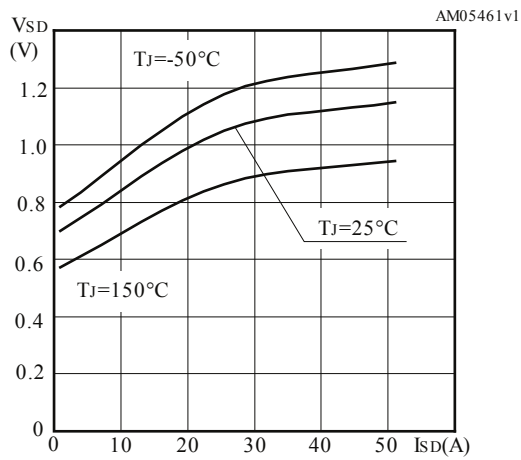
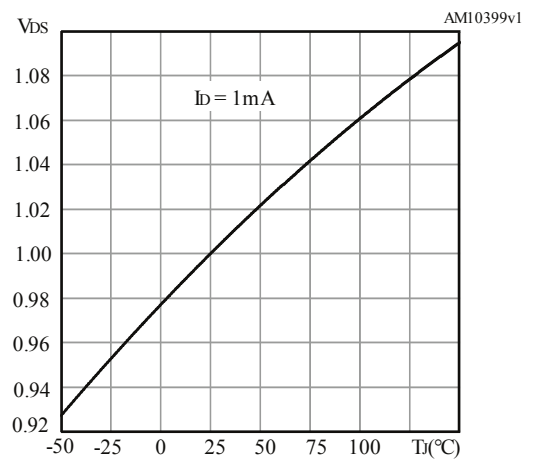
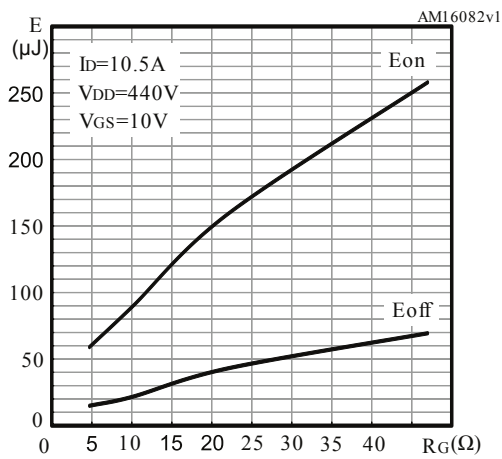
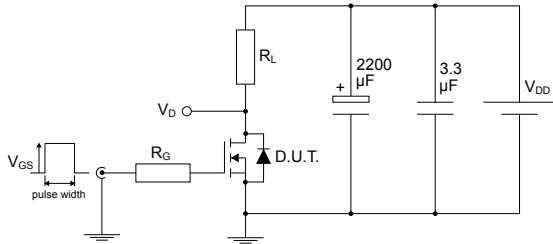
Figure 8. Gate charge vs gate-source voltage

Figure 9. Static drain-source on resistance

Figure 10. Capacitance variations

Figure 11. Output capacitance stored energy

Figure 12. Normalized on-resistance vs temperature

Figure 13. Normalized gate threshold voltage vs temperature


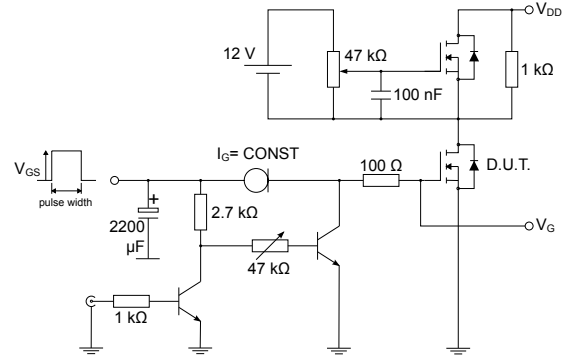
Figure 14. Drain-source diode forward characteristics

Figure 15. Normalized $V_{(BR)DSS}$ vs temperature

Figure 16. Switching energy vs gate resistance


* E_{on} including reverse recovery of a SiC diode

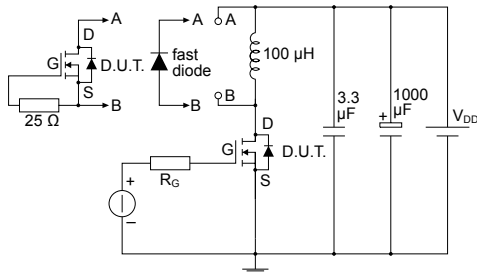
3 Test circuits

Figure 17. Test circuit for resistive load switching times


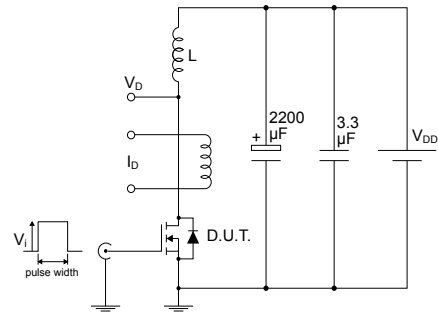
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Figure 18. Test circuit for gate charge behavior


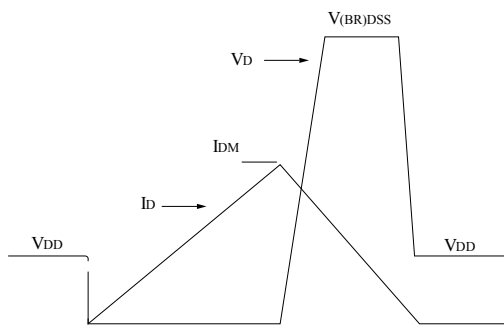
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Figure 19. Test circuit for inductive load switching and diode recovery times


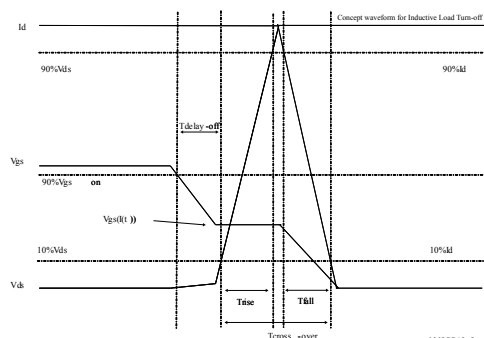
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Figure 20. Unclamped inductive load test circuit


AM01471v1

Figure 21. Unclamped inductive waveform


AM01472v1

Figure 22. Switching time waveform


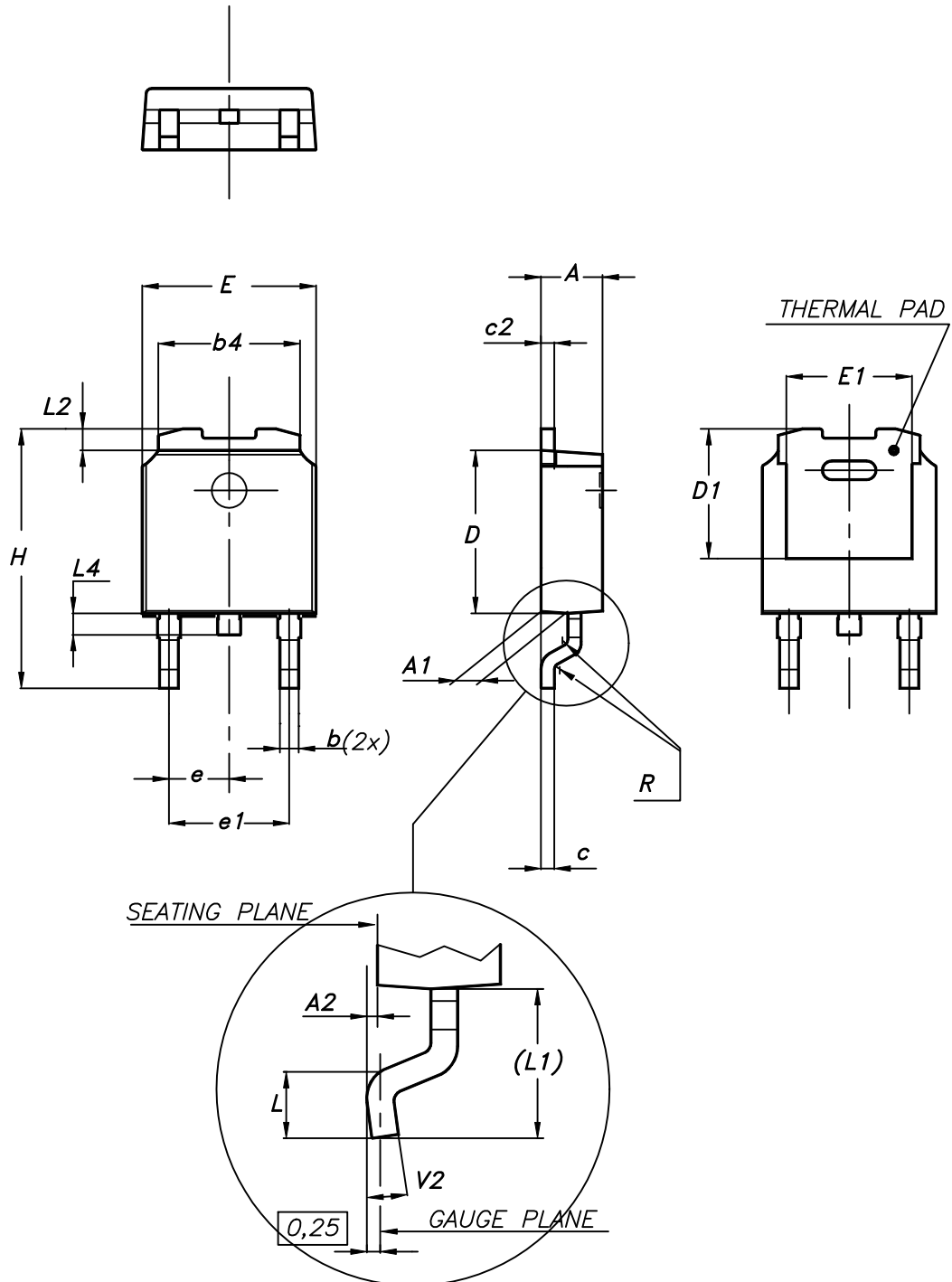
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4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

4.1 DPAK (TO-252) type A2 package information

Figure 23. DPAK (TO-252) type A2 package outline



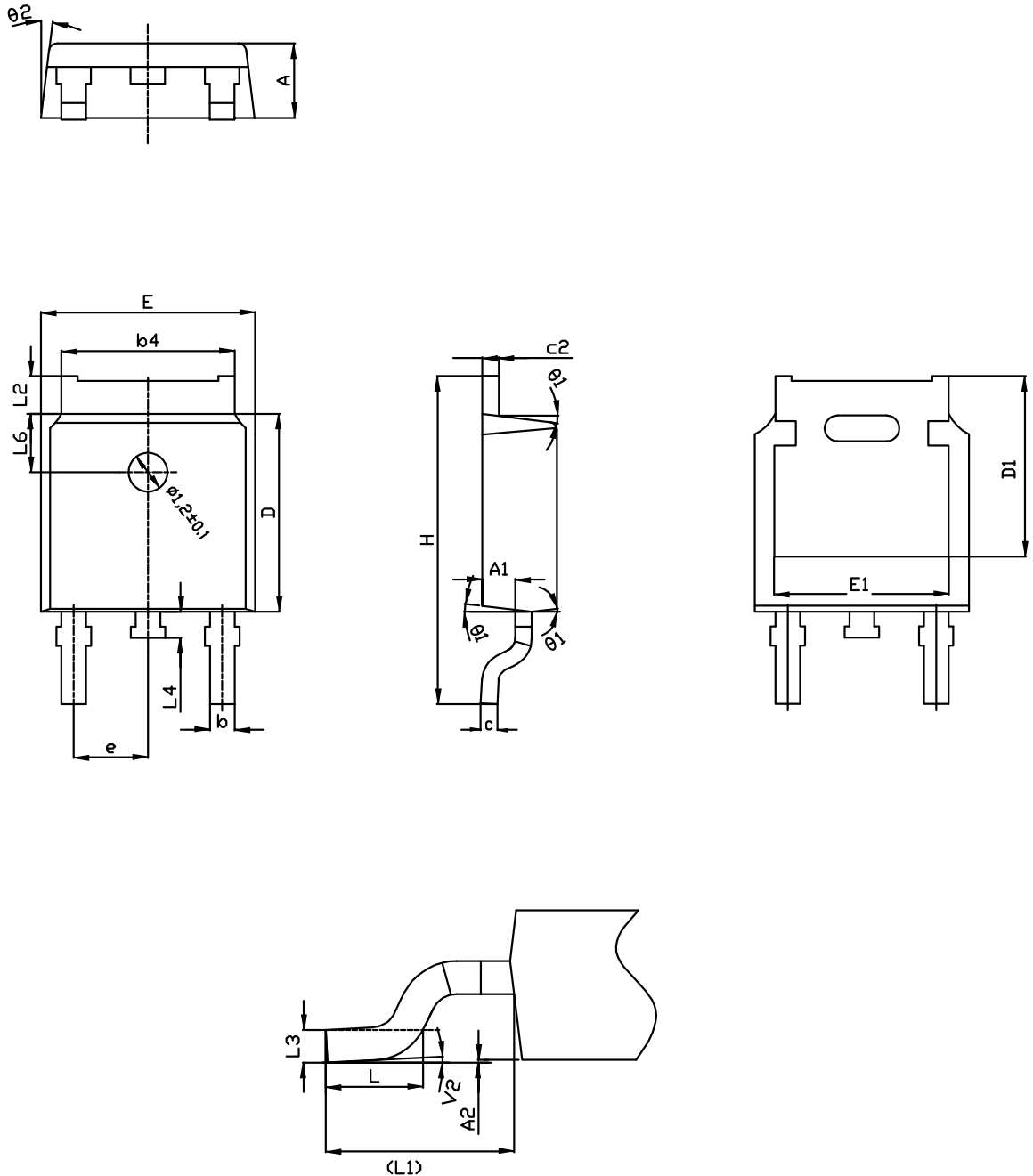
0068772_type-A2_rev25

Table 8. DPAK (TO-252) type A2 mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | 4.95 | 5.10 | 5.25 |
| E | 6.40 | | 6.60 |
| E1 | 5.10 | 5.20 | 5.30 |
| e | 2.159 | 2.286 | 2.413 |
| e1 | 4.445 | 4.572 | 4.699 |
| H | 9.35 | | 10.10 |
| L | 1.00 | | 1.50 |
| L1 | 2.60 | 2.80 | 3.00 |
| L2 | 0.65 | 0.80 | 0.95 |
| L4 | 0.60 | | 1.00 |
| R | | 0.20 | |
| V2 | 0° | | 8° |

4.2 DPAK (TO-252) type C2 package information

Figure 24. DPAK (TO-252) type C2 package outline



0068772_C2_25

Table 9. DPAK (TO-252) type C2 mechanical data

| Dim. | mm | | |
|------|----------|-------|-------|
| | Min. | Typ. | Max. |
| A | 2.20 | 2.30 | 2.38 |
| A1 | 0.90 | 1.01 | 1.10 |
| A2 | 0.00 | | 0.10 |
| b | 0.72 | | 0.85 |
| b4 | 5.13 | 5.33 | 5.46 |
| c | 0.47 | | 0.60 |
| c2 | 0.47 | | 0.60 |
| D | 6.00 | 6.10 | 6.20 |
| D1 | 5.10 | | 5.60 |
| E | 6.50 | 6.60 | 6.70 |
| E1 | 5.20 | | 5.50 |
| e | 2.186 | 2.286 | 2.386 |
| H | 9.80 | 10.10 | 10.40 |
| L | 1.40 | 1.50 | 1.70 |
| L1 | 2.90 REF | | |
| L2 | 0.90 | | 1.25 |
| L3 | 0.51 BSC | | |
| L4 | 0.60 | 0.80 | 1.00 |
| L6 | 1.80 BSC | | |
| θ1 | 5° | 7° | 9° |
| θ2 | 5° | 7° | 9° |
| V2 | 0° | | 8° |

4.3 DPAK (TO-252) type E package information

Figure 25. DPAK (TO-252) type E package outline

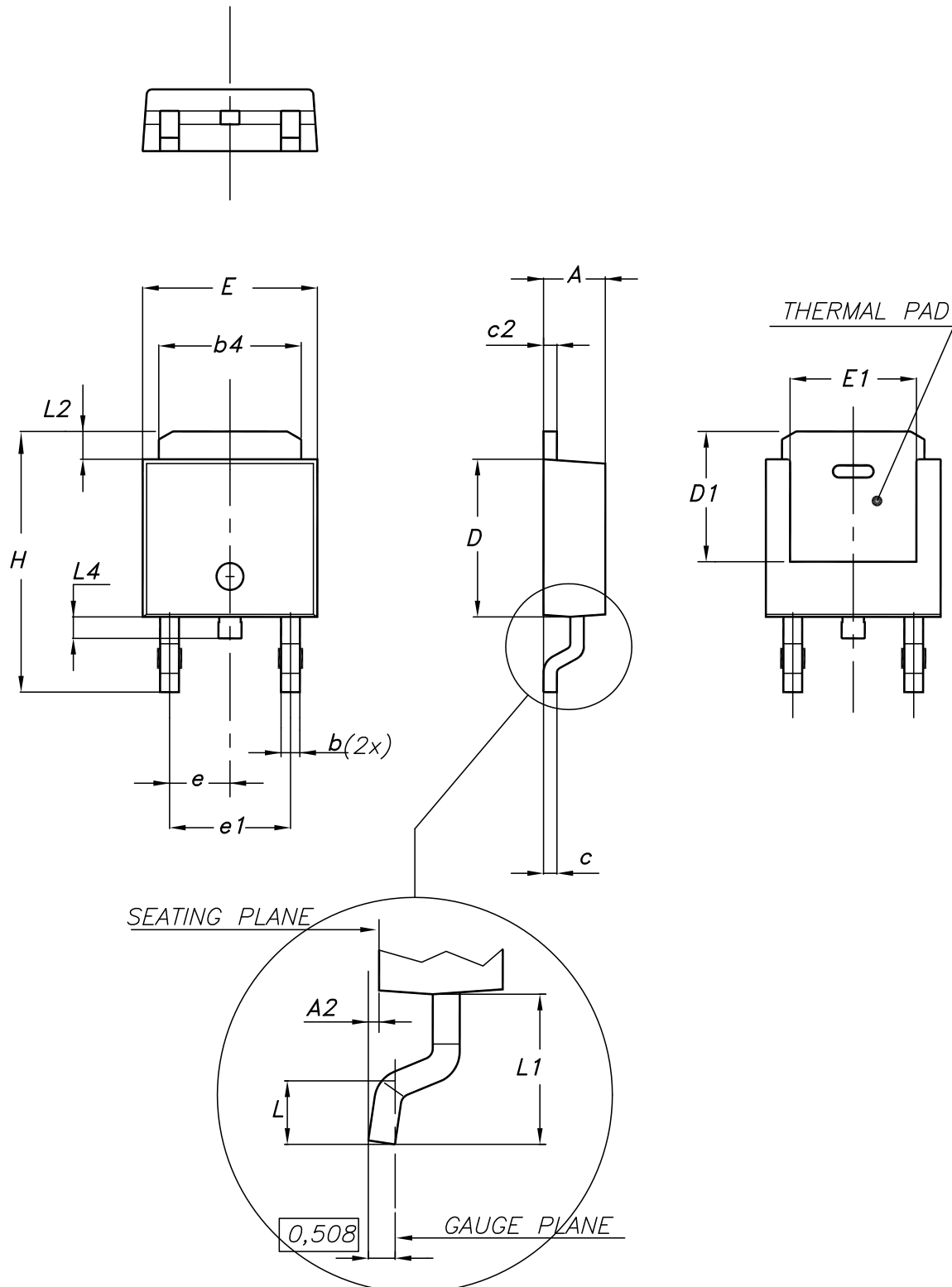
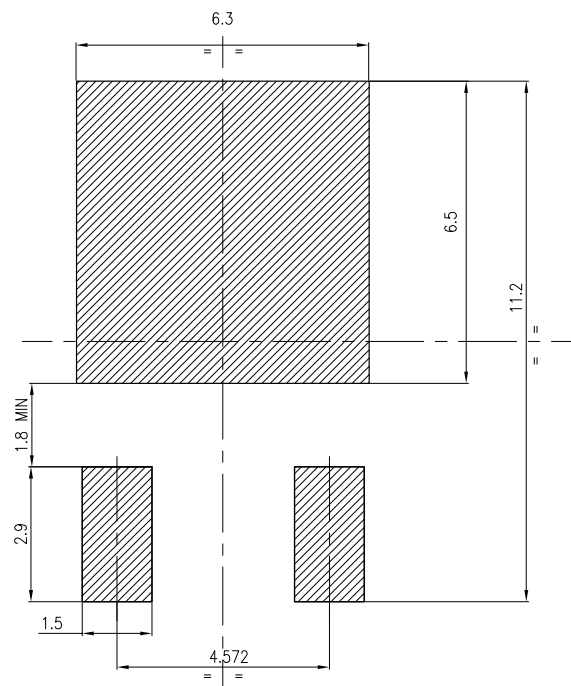


Table 10. DPAK (TO-252) type E mechanical data

| Dim. | mm | | |
|------|------|-------|-------|
| | Min. | Typ. | Max. |
| A | 2.18 | | 2.39 |
| A2 | | | 0.13 |
| b | 0.65 | | 0.884 |
| b4 | 4.95 | | 5.46 |
| c | 0.46 | | 0.61 |
| c2 | 0.46 | | 0.60 |
| D | 5.97 | | 6.22 |
| D1 | 5.21 | | |
| E | 6.35 | | 6.73 |
| E1 | 4.32 | | |
| e | | 2.286 | |
| e1 | | 4.572 | |
| H | 9.94 | | 10.34 |
| L | 1.50 | | 1.78 |
| L1 | | 2.74 | |
| L2 | 0.89 | | 1.27 |
| L4 | | | 1.02 |

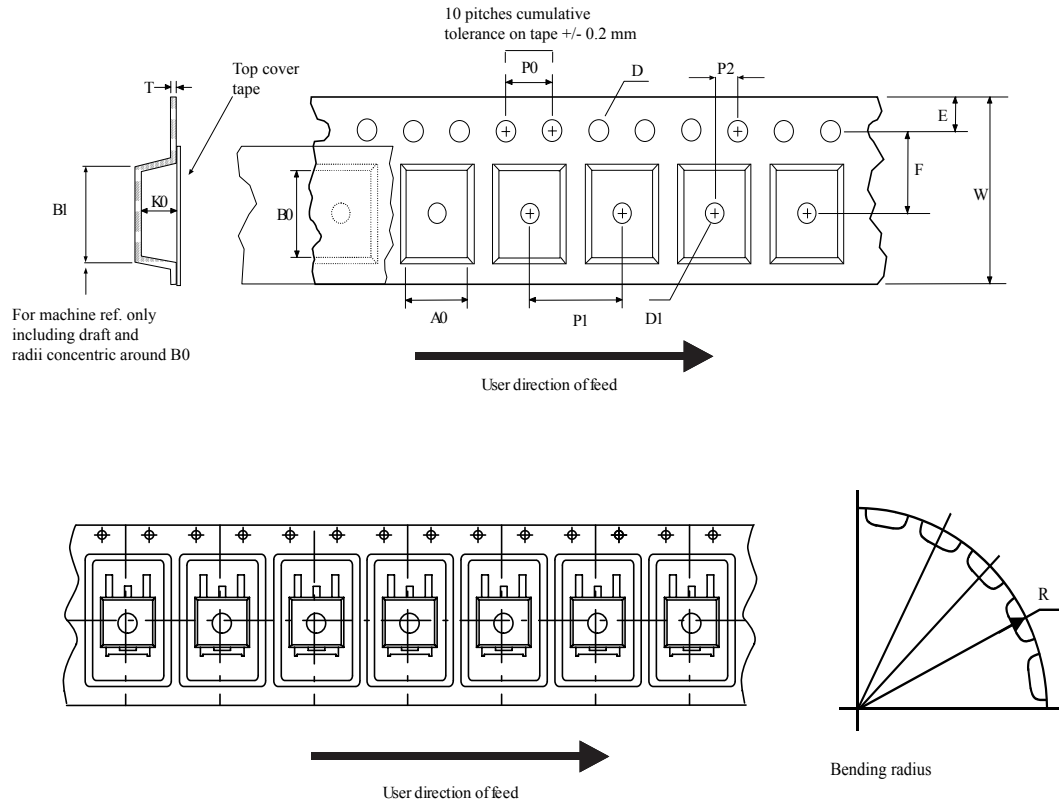
Figure 26. DPAK (TO-252) recommended footprint (dimensions are in mm)



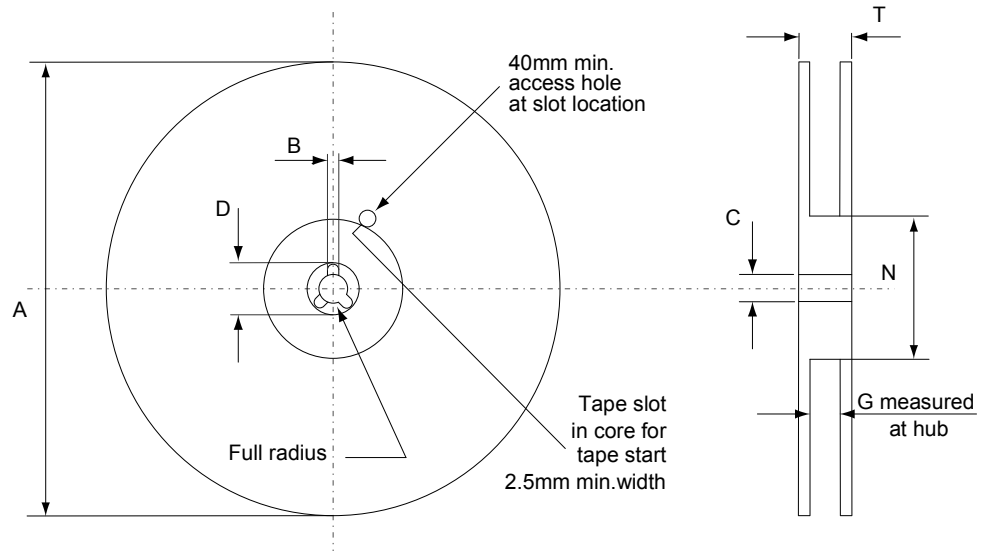
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4.4 DPAK (TO-252) packing information

Figure 27. DPAK (TO-252) tape outline



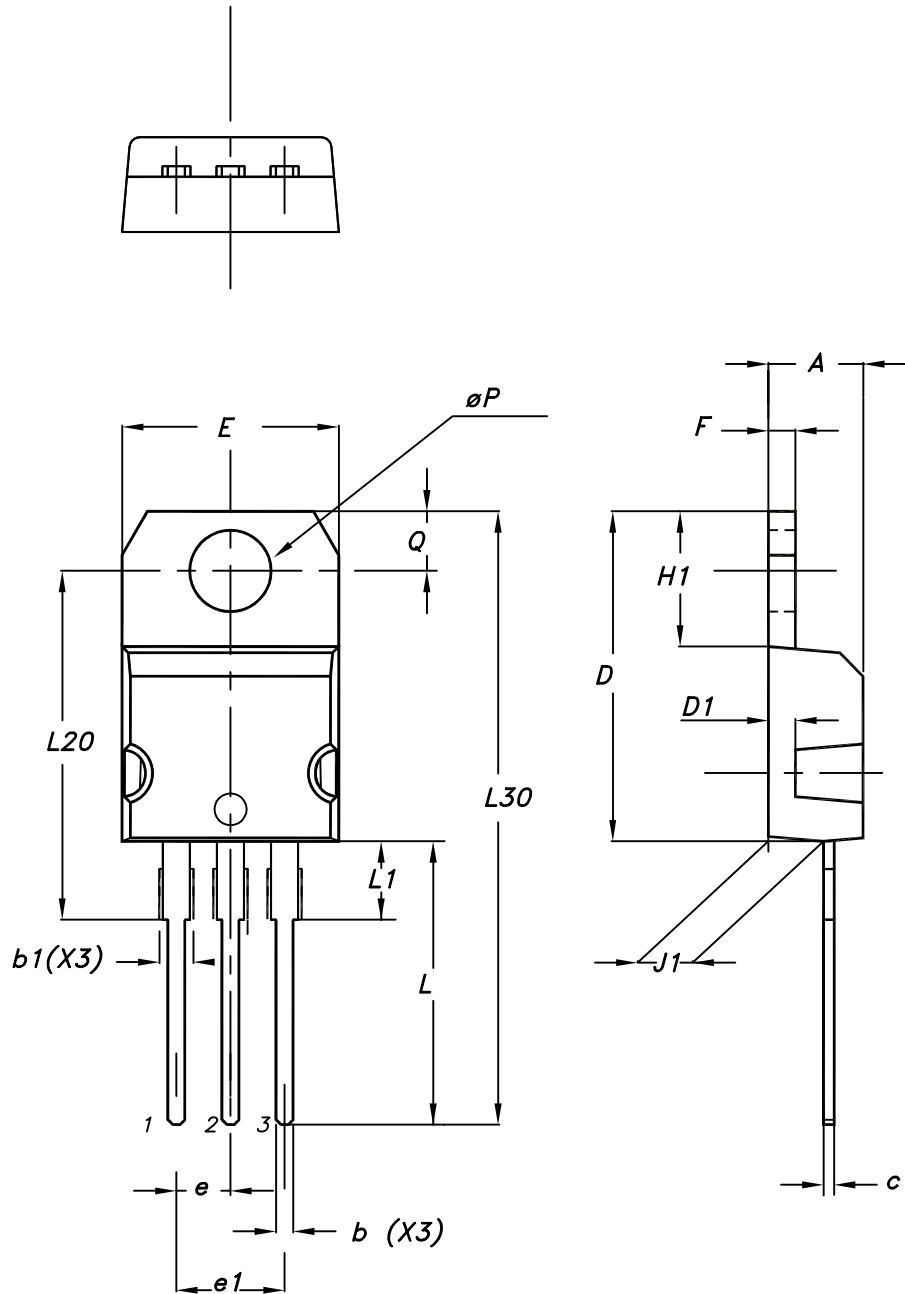
AM08852v1

Figure 28. DPAK (TO-252) reel outline


AM06038v1

Table 11. DPAK (TO-252) tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|-----------|------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 6.8 | 7 | A | | 330 |
| B0 | 10.4 | 10.6 | B | 1.5 | |
| B1 | | 12.1 | C | 12.8 | 13.2 |
| D | 1.5 | 1.6 | D | 20.2 | |
| D1 | 1.5 | | G | 16.4 | 18.4 |
| E | 1.65 | 1.85 | N | 50 | |
| F | 7.4 | 7.6 | T | | 22.4 |
| K0 | 2.55 | 2.75 | | | |
| P0 | 3.9 | 4.1 | Base qty. | | 2500 |
| P1 | 7.9 | 8.1 | Bulk qty. | | 2500 |
| P2 | 1.9 | 2.1 | | | |
| R | 40 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 15.7 | 16.3 | | | |

4.5 TO-220 type A package information
Figure 29. TO-220 type A package outline


0015988_typeA_Rev_21

Table 12. TO-220 type A package mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| b | 0.61 | | 0.88 |
| b1 | 1.14 | | 1.55 |
| c | 0.48 | | 0.70 |
| D | 15.25 | | 15.75 |
| D1 | | 1.27 | |
| E | 10.00 | | 10.40 |
| e | 2.40 | | 2.70 |
| e1 | 4.95 | | 5.15 |
| F | 1.23 | | 1.32 |
| H1 | 6.20 | | 6.60 |
| J1 | 2.40 | | 2.72 |
| L | 13.00 | | 14.00 |
| L1 | 3.50 | | 3.93 |
| L20 | | 16.40 | |
| L30 | | 28.90 | |
| øP | 3.75 | | 3.85 |
| Q | 2.65 | | 2.95 |

5 Ordering information

Table 13. Order codes

| Order code | Marking | Package | Packing |
|------------|---------|---------|---------------|
| STD18N55M5 | 18N55M5 | DPAK | Tape and reel |
| STP18N55M5 | | TO-220 | Tube |

Revision history

Table 14. Document revision history

| Date | Version | Changes |
|-------------|---------|--|
| 09-Feb-2010 | 1 | First release. |
| 04-Mar-2011 | 2 | <ul style="list-style-type: none"> – Document status promoted from preliminary data to datasheet; – Added new package, mechanical data: D²PAK. |
| 22-Nov-2013 | 3 | <ul style="list-style-type: none"> – Updated: title on the cover page and RDS(on) values. – Modified: EAS value and note 3 in Table 2 – Modified: RDS(on) value in Table 4, typical values in Table 5 and 7 – Updated: the entire Table 5 – Added: Section 2.1: Electrical characteristics (curves) – Updated: Section 4: Package mechanical data and Section 5: Packaging mechanical data – Updated: Figure 11 and 18 – Minor text changes. |
| 03-Aug-2018 | 4 | <p>The part numbers STB18N55M5 and STF18N55M5 have been moved to a separate datasheet.</p> <p>Removed maturity status indication from cover page. The document status is production data.</p> <p>Updated title in cover page, Section 1 Electrical ratings, Section 2 Electrical characteristics and Section 4 Package information.</p> <p>Minor text changes.</p> |

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